

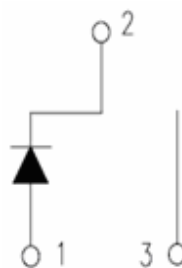
SMBD001030 SCHOTTKY RECTIFIER

Features:

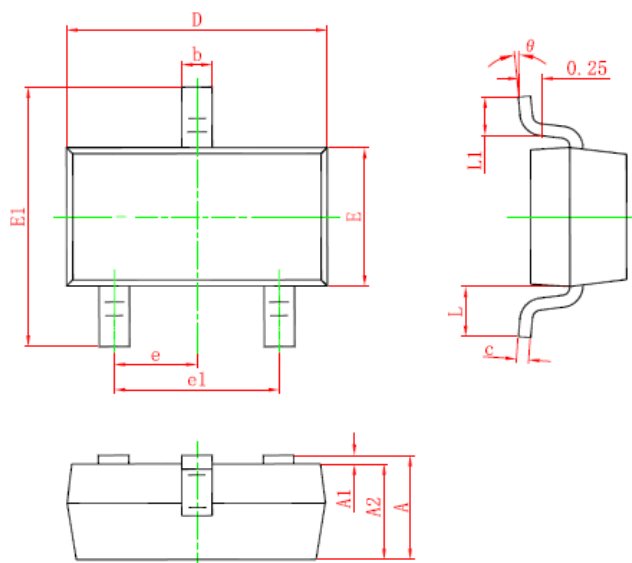
- Schottky Barrier Chip
- Extremely Low Minority Carrier Lifetime
- Very Low Capacitance
- Low Reverse Leakage
- High-efficiency
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data:

- Case: Molded Plastic
- SOT-23 Surface Mount Package
- Approximate Weight: 0.015 grams
- Packaging: Tape and Reel



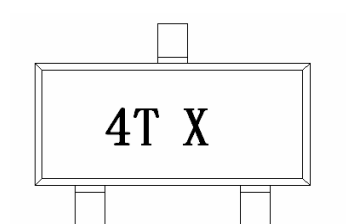
Mechanical Dimensions: In mm / Inches



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23(CJ)

Marking Diagram:



Where X is Date Code

4T = Part Name

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SMBD001030	SOT-23(Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Peak Reverse Voltage	V _R	30	V
Average Rectified Output Current	I _{F(AV)}	0.01	A
Forward Voltage @I _F = 10mA, T _A = 25°C @I _F = 10mA, T _A = 125°C	V _{FM}	0.70 0.45	V
Peak Reverse Current @ V _R =25V, T _A = 25°C	I _{RM}	0.2	μA
Total Device Dissipation @ T _A = 25°C	P _F	200	mW
Total Capacitance (V _R = 15 V, f = 1.0 MHz)	C _T	2	pF
Operating Junction Temperature Range	T _J	-55 to +125	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C
Case Style	SOT-23		

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